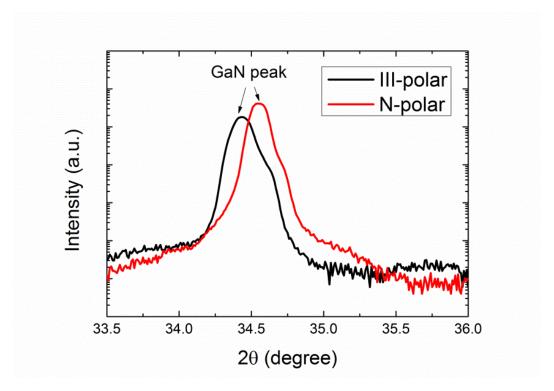
## **Supplementary Materials**

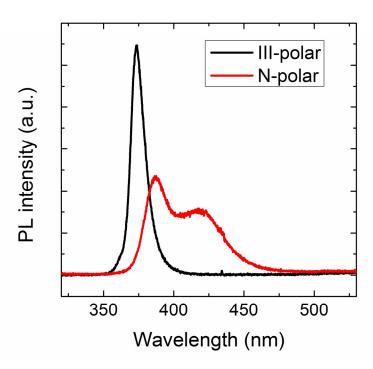
## On the Luminescence Properties and Surface Passivation Mechanism of III- and N-Polar Nanopillar Ultraviolet Multiple-Quantum-Well Light Emitting Diodes

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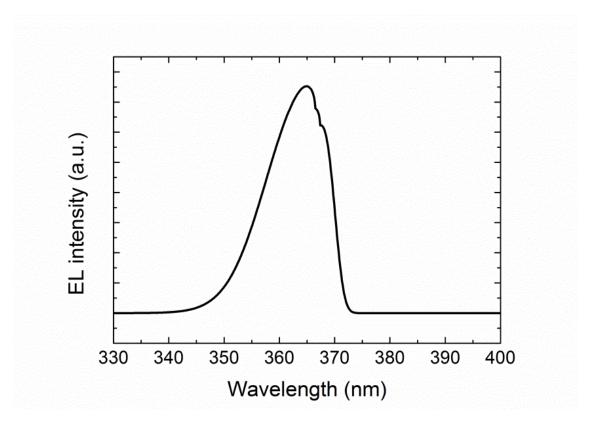
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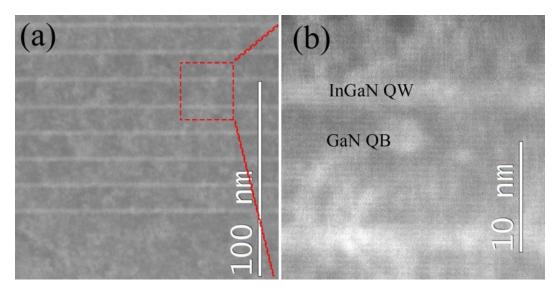


**Figure S1.** HRXRD symmetric  $\omega$ -2 $\theta$  scans of III- and N-polar MQW samples.

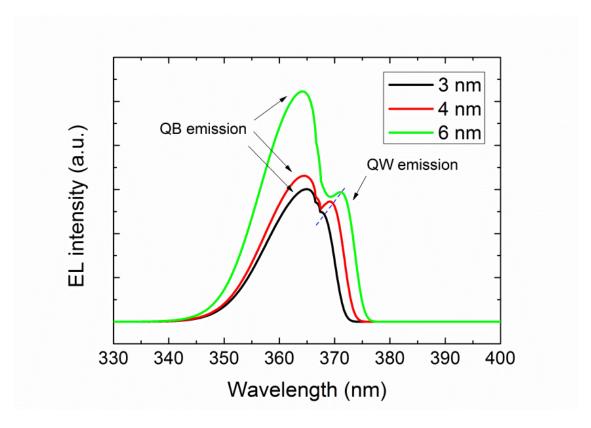


**Figure S2.** RT PL spectra of planar III-polar and N-polar MQW samples. Peak positions and shapes are almost identical to those of nanostructured samples.





**Figure S4.** HAADF-STEM image of planar III-polar MQW samples with low magnification (a) and zoom-in view (b) of the individual QW and QB.



**Figure S5.** Simulated electroluminescence spectra of UVA-LED with In<sub>0.03</sub>Ga<sub>0.97</sub>N/GaN MQWs of varying QW thicknesses. A small red shift of less than 7 nm is observed when doubling the QW thickness.